NSN 5961-00-006-1516

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nclosure Material:
Metal
Overall Length:
0.468 inches
Overall Diameter:
0.380 inches
Mounting Facility Quantity:
1
nternal Configuration:
Junction contact
Electrode Internally-electrically Connected To Case:
Base
Mounting Method:
Threaded stud
Terminal Circle Diameter:
0.215 inches
Features Provided:
Hermetically sealed case
Overall Width Across Flats:
0.437 inches
Thread Size:
0.190 inches
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
100.0 breakdown voltage, collector-to-base, emitter open and 80.0 breakdown voltage, collector-to-emitter, base open and 5.5
preakdown voltage, emitter-to-base, collector open
Current Rating Per Characteristic:
100.00 milliamperes source cutoff current
Power Rating Per Characteristic:
30.0 watts small-signal input power, common-collector
Maximum Operating Tempurature Per Measurement Point:
200.0 degrees celsius junction
Special Features:
Junction pattern arrangement: pnp
Test Data Document:
96214-537547 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.,
excludes any specification, standard or other document that may be referenced in a basic governing drawing)
Thread Series Designator:
Jnf
Terminal Type And Quantity:
3 tab solder lug

N/a

Shelf Life:

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In	18	<i>(</i>)+	МЛО	201	ure:

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Demilitarization:

No

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